Doping change and distortion e ect on double-exchange ferrom agnetism

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D oping change and distortion e ect on the double-exchange ferrom agnetism are studied within a simpli ed double-exchange m odel. The presence of distortion is m odelled by introducing the Falicov-K in ball interaction between itinerant electrons and classical variables. By employing the dynam ical m ean-eld theory the charge and spin susceptibility are exactly calculated. It is found that there is a competition between the double-exchange induced ferrom agnetism and disorder-order transition. At low temperature various long-range order phases such as charge ordered and segregated phases coexist with ferrom agnetism depending on doping and distortion. A rich phase diagram is obtained.

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I. IN TRODUCTION

The discovery of colossalm agnetoresistance in doped m anganites^{1,2} has renew ed interest in the ferrom agnetism induced by the double-exchange (DE) mechanism.³ The main feature of the DE mechanism is a cooperative effect where electron hoping favors ferrom agnetic (FM) ordering of localized spins via the FM Hund coupling, and vice versa, the presence of the FM order facilitates the electron hoping. The occurrence of metallic FM state in doped manganites $R_1 _x A_x M nO_3$ (where R is a trivalent rare-earth element and A is a divalent alkaline ion) was qualitatively explained by the DE mechanism. The physically relevant electrons in these com pounds are those from Mn 3d levels which are split by the cubic crystalline eld into triply degenerate t_{2g} levels and doubly degenerate eq levels. E lectrons of eq levels are able to hop between Mn sites and form the conduction band, while electrons of t_{2q} levels are localized. Conduction electrons and localized spins are correlated by the DE mechanism which leads to the appearance of the metallic FM phase. The DE m odel became the starting point tow ard com prehensive understanding of the properties of doped m anganites.

Experim ents have observed in doped m anganites a very rich phase diagram, which involves phases with spin, charge and orbital orders.¹ For the undoped case (x = 0)allM n ions are M n³⁺ and are expected to induce a Jahn-Teller (JT) distortion. For the other extrem e doping (x = 1) all M n ions are M n⁴⁺ and do not couple to the JT distortion. In the regime of intermediate doping, two valence ions $M n^{3+}$ and $M n^{4+}$ are simultaneously present. The presence of two valence ions may lead to a static mixed valence M $\mathrm{n^{3+}}\,/\mathrm{M}\,\mathrm{n^{4+}}\,$ con guration, in particular, to an alternation charge-ordered (CO) state of M n³⁺ /M n⁴⁺ ions for appropriate dopings. This is the conventional view, for which there are abundant experimental and theoretical supports.^{1,2} In particular, recently a CO-FM state has been observed.⁵ However, there are several experiments which challenge the conventional view. Several x-ray absorption^{6,7,8,9} and neutron di raction studies¹⁰ revealed pictures that do not m atch with the static mixture of M n^{3+} and M n^{4+} ions.

One suggests that all M n ions have the same valence and result into the Zener-polaron state.^{11,12} However, very recent experiment⁸ observed the presence of two types of M n sites with di erent local geom etric structures. One of the types of Mn sites is surrounded by a tetragonal-distorted oxygen octahedron, whereas the other has a regular octahedral environment. As a result a charge segregation state was deduced. W ith the m otivation of the experim ental observations⁸ we m odel the presence of the two types of M n sites by incorporating the Falicov-K im ball (FK) m odel.¹³ The FK m odel was initially introduced as a statistical model for metalinsulator transition.¹³ Later it was also applied to valence change transitions in interm etallic com pounds.^{14,15} W ithin the FK model the presence of two types of M n sites is mapped to a classical variable which only accept two values (for instance, 1 and 0). The energy di erence of these sites is mapped into the interaction strength of the FK model. Indeed, the sites surrounded by tetragonal-distorted octahedron have induced the JT distortion. As a consequence the energy levels of the distorted Mn sites are split. The FK model can describe a charge ordered phase as well as a charge segregated phase.¹⁶ In particular, the model can exhibit the checkerboard CO state in appropriate conditions. The checkerboard CO state is truly a mixed-valence state. The segregated state is a phase-separated m ixture of two full uniform con gurations.^{17,18,19,20} In such the way, at low tem perature the FK model could establish various phases with di erent charge con gurations which may correspond to the experim ental observations.8

However, the FK model alone cannot describe the DE induced FM state which was also observed in doped manganites. Therefore we incorporate the FK model into the DE model in order to study both the charge ordered phases and the ferrom agnetism upon doping. The combined model has previously been considered in the context of order-disorder change of the A-site substitution.²¹ In the previous study²¹ only the checkerboard CO and FM state are considered in the limit of in nite value of the Hund coupling. In this paper we study all possible ordered phases of the combined model in whole range of doping and interaction. In order to detect the phase transition we study the static charge and spin response of system within the dynam icalmean eld theory (DMFT).²² The DMFT has been widely used for investigating strongly correlated electron systems. Within the DMFT the static charge and spin correlation function are calculated explicitly. We nd that the system exhibits a rich phase diagram which includes various charge ordered phases coexisting with ferrom agnetism. In particular, the checkerboard CO state or the segregated state can coexist with the FM state. The combined m odel can also serve as a m odel for studying the problem of order-disorder A – site substitution²¹ or the problem of orbital ordering in doped m anganites.^{23,24}

The present paper is organized as follows: In Sec. II we present the combined FK and DE model and its DM FT solutions. In Sec. III the charge and spin correlation functions are calculated explicitly. The numerical results and discussions are presented in Sec. IV. The nalsection is conclusion and remark.

II. M ODEL AND DYNAM ICAL MEAN-FIELD THEORY

The combined FK and DE model in our study is described by the following Ham iltonian

$$H = t \begin{array}{ccc} X & X & X & X \\ H = t & c_{i}^{y} c_{j} & c_{i}^{y} c_{i} & 2J_{H} & S_{i}^{z} s_{i}^{z} \\ & & & \\ & & X & X & & i \\ & & +U & n_{i} w_{i} + E_{w} & w_{i}; & & (1) \\ & & & i & & \end{array}$$

where c_i^y (c_i) is the creation (annihilation) operator for an itinerant electron with spin at lattice site i. The rst term in Hamiltonian (1) represents the hoping of it inerant electrons between the nearest neighbor sites. t is the hoping integral and is scaled with the spatial dimension d as $t = t^2 = (2^2 d)^{26}$. In the following we will take $t^2 = 1$ as the unit of energy. S_i^z is the z com ponent of localized spin at lattice site i. For simplicity, it takes two values 1;1. $s_i^z = (c_{ii}^y c_{ii} - c_{iii}^y c_{iii}) = 2$ is the z component of itinerant electron spin. w_i is a classical variable that assum as the value 1(0) if site i is surrounded by distorted (regular) octahedron. U is the interaction strength and is mapped into the di erence in the level energy of these sites. The expectation value w = , hw i i=N , (N is the num ber of lattice sites), corresponds to the concentration of distorted sites. The chem -_i hn₁ i=N, ical potential controls the doping $n_e =$ while E w controls the fraction of distorted sites. The condition $n_e + w = 1$ is used to determ in E_w for each doping ne. The rst three terms in Ham iltonian (1) describe a simplied DE model which contains only the Ising-type interaction between the itinerant and localized electron spins. The simplication does not allow any spin-ip processes, which can be important at low temperature where spin-wave excitations may govern the therm odynam ics of the system . How ever, in the DE processes spins

of itinerant electrons align ferrom agnetically with the localized spins, hence the Ising part of the Hund coupling plays a dom inant role. W ithin the DMFT the simpli ed DE model is equivalent to the DE model with classical localized spins in the disordered param agnetic phase. The transport quantities calculated within the simpli ed m odel capture essential features of the full DE m odel.²⁷ The sim pli ed DE m odel has also previously been used in the study of doped m anganites.²⁸ The last two terms in Ham iltonian (1) take into account the energy di erence of M n sites. They together with the hoping term form the FK model.¹³ Several authors have also constructed the combined model to study the properties of manganites in di erent contexts and regim es.^{21,23,24,25} Ferrari et al. used the combined model to study the metallic FM phase of the two orbital DE model.²⁴ Recently, Ram akrishnan et al. basically used the combined m odel to construct a two band model of localized polaronic and broad band states.²⁵ They used the DMFT to calculate transport quantities and explained the metal insulator transition and the colossal magnetoresistance in doped m anganites.²⁵

W e solve the combined model (1) by the DM FT 22 The DM FT is based on the in nite dimension limit. In the in nite dimension limit the self-energy is pure local and does not depend on momentum. The G reen function of itinerant electrons with spin satisfies the D yson equation

G
$$(k; i!_n) = \frac{1}{i!_n (k) + (i!_n)};$$
 (2)

where $(k) = 2t \Big|_{i=1,d}^{P} \cos(k_i)$ is the dispersion of free itinerant electrons on a hypercubic lattice, and $(i!_n)$ is the self energy which depends only on frequency. The self energy is determined by solving an elective singlesite problem. The action for this elective problem is

$$Z Z X X S_{e} = d d^{0} c^{y} ()G^{1} (^{0})c (^{0})$$

$$Z X G^{1} (^{0})c (^{0}) C^{2} (^{0}) C$$

where G (⁰) is the G reen function of the e ective medium. It plays as the bare G reen function of the e ective problem. The local G reen function also satis es the D yson equation

$$G^{-1}(i!_{n}) = G^{-1}(i!_{n}) \qquad (i!_{n}); \qquad (4)$$

where G $(i!_n)$ is the Fourier transform of G (). The local Green function G $(i!_n)$ of the elective single-site problem is solely determined by the partition function

$$G (i!_{n}) = \frac{\ln Z_{e}}{G^{-1}(i!_{n})};$$
(5)

where Z_e is the partition function of the e ective problem (3). The self-consistent condition of the DM FT requires that the local G reen function G (i!_n) obtained within the elective problem must coincide with the local G reen function of the original lattice, i.e.,

$$G (i!_{n}) = \frac{1}{N} X G (k;i!_{n})$$

$$= d (\frac{1}{i!_{n}} + (i!_{n}); (6)$$

where () is the density of state (DOS) of noninteracting itinerant electrons. In the in nite dimension limit of hypercubic lattices it has the form () = $\exp(\frac{2}{2}(t^2)^2) = t^2$. Eqs. (4), (5) and (6) form the self-consistent equations for determining the self-energy, and hence, also the G reen function of the original lattice. W ithin the elective single-site problem, the partition function is

$$Z_{e} = Tr Dc^{y}Dc e^{S_{eff}};$$
 (7)

where the trace is taken over S $^{\rm z}$ and w. This partition function can be calculated exactly. It is sim ilar to solve the FK model within the DM FT 29 W e obtain

$$Z_{e} = 2 \qquad \exp \qquad E_{w} + \frac{z_{e} = 0; 1 s = 1}{\sum_{n} \sum_{n} \frac{Z_{n}(\underline{i!}_{n}) + sJ_{H} - U_{n}}{\underline{i!}_{n}};(8)$$

where Z (i!_n) G¹(i!_n). Using Eq. (5) we obtain the local G reen function

G (i!_n) =
$$\frac{X}{s} \frac{W_{s}}{Z_{s}(i!_{n}) + sJ_{H} U}$$
; (9)

where the weight factors W $_{\rm s}$ are

$$W_{s} = \frac{2}{Z_{e}} \exp \left(E_{w} + \frac{X}{n} \ln \frac{Z(\underline{i!}_{n}) + sJ_{H}}{\underline{i!}_{n}} \right)$$
(10)

with = 0;1 and s = 1. Note that the weight factors W_s are not simply a number. They are functionals of the local G reen function. This is an important feature of the DMFT that gives nontrivial contributions to the response functions of the system 29 In the param agnetic phase Z_{*} (i!_n) = Z_# (i!_n), hence W_s = W_{; s} that leads the G reen function (9) and the self energy are independent of spin indeces, as expected. The value of E_w is adjusted that the concentration w full lls n_e + w = 1 for each doping n_e. O ne can show that

$$W = \begin{matrix} X \\ W _{1s} : \\ s = 1 \end{matrix}$$
(11)

W e use this equation to adjust the value of E $_{\rm W}$. So far, we have obtained closed system of equations for determining the G reen function of the system. The system of equations can be solved num erically by iterations.¹⁶

III. IN STABILITY OF HOM OGENEOUS PARAMAGNETIC PHASE

In order to detect the charge and spin ordered states which are established at low temperature we study the static charge and spin correlation function of itinerant electrons in disordered param agnetic phase. The signal of a phase transition is a divergence of these correlation functions at a certain momentum. The charge (c) and spin (s) correlation function are de ned as

$$c^{(s)}(i;j) = (n_{i''} n_{i\#})(n_{j''} n_{j\#});$$
 (12)

where $n_i = n_i$ hn_i i. These correlation functions can be expressed as

$$^{c(s)}(\mathbf{i};\mathbf{j}) = \bigvee_{0}^{c(s)}(\mathbf{i};\mathbf{j}) \circ; \quad (13)$$

where $\circ(i; j) = n_i n_j \circ$, and = 1 for the charge correlation function and = for the spin correlation function. In order to calculate the static correlation functions, one has to introduce external elds h_i which couple to n_i into the H am iltonian. The correlation functions $\circ(i; j)$ are obtained by di erentiating the G reen function with respect to the external elds and then taking the zero limit of the elds,²⁹ i.e.,

$$\circ (i; j) = T^{2} \prod_{n}^{X} \frac{dG_{ii;}(i!_{n})}{dh_{j} \circ}_{fhg=0} :$$
(14)

Following the standard technique, 16,29 one can express the charge and spin correlation function in the terms of the charge and spin susceptibility $^{c(s)}(q;i!_n)$

$$c^{(s)}(q) = T^{2} \prod_{n}^{X} c^{(s)}(q; i!_{n});$$
 (15)

where c(s) (q) is the static charge (spin) correlation function in momentum space. From the de nition of charge and spin correlation function (13) and relation (14), we obtain

$${}^{c(s)}(q;i!_{n}) = 2_{0}(q;i!_{n}) + {}_{0}(q;i!_{n}) \frac{1}{2} X_{0} \frac{d(i!_{n})}{dG_{0}(i!_{n})} = {}_{0}{}^{c(s)}(q;i!_{n});(16)$$

where $_{0}(q; i!_{n}) = {}^{P}_{k} G (k + q; i!_{n})G (k; i!_{n})$ is the bare particle-hole susceptibility. Here we have used the fact that in the param agnetic phase

$$d_{\#}(i!_{n}) = dG_{\#}(i!_{n}) = d_{\#}(i!_{n}) = dG_{\#}(i!_{n}); \quad (17)$$

$$d_{*}(i!_{n}) = dG_{*}(i!_{n}) = d_{*}(i!_{n}) = dG_{*}(i!_{n}): (18)$$

From Eqs.(4) and (9), we obtain the self-energy (i!_n) as a functional of G (i!_n) and W $_{s}$, hence its full deriva-

tives in Eq. (16) are expressed through its partial derivatives. We obtain

$$\frac{d}{dG} \left(\underbrace{i!}_{n} \right)_{W} = \sum_{n} \circ \frac{\theta}{\theta} \left(\underbrace{i!}_{n} \right)_{W} + \frac{X}{s} \left(\underbrace{\theta}_{W} \left(\underbrace{i!}_{s} \right)_{G} \right)_{W} - \underbrace{W}_{S} \left(\underbrace{\theta}_{W} \left(\underbrace{i!}_{s} \right)_{G} \right)_{W} - \underbrace{W}_{S} \left(\underbrace{\theta}_{W} \left(\underbrace{i!}_{s} \right)_{W} \right)_{W} \right)$$
(19)

where W -s m eans all weight factors W except W s. Substituting (19) into Eq. (16) we arrive at

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where the matrix elements of b (q) are

$$_{s}(\mathbf{q}) = \frac{\mathbf{X}}{\mathbf{G} \circ (\mathbf{i!})} \quad \mathbf{s} \circ \mathbf{C}^{(s)}(\mathbf{q};\mathbf{i!}) : \quad (21)$$

The functional derivative of W $_{\rm S}$ in the above equation can explicitly be expressed through the derivatives of W $_{\rm S}$ with respect to Z (i! $_{\rm n}$) and the partial derivatives of the self energy (i! $_{\rm n}$).²⁹ Substituting (20) into (21) and perform ing som e algebraic calculations we obtain the follow ing m atrix equation

$$\oint (q)b(q) = \oint (q);$$
 (22)

where the matrixes $\overset{}{\Phi}(q)$, $\overset{}{P}(q)$ have the following elements

$$Q_{s; 0s^{0}}(q) = s_{; 0s^{0}}(q) = s_{; 0s^{0}}(q) = s_{; 0s^{0}}(q) = s_{; 0s^{0}}(q) = x_{s; 0s^{0}}(q$$

Here we have introduced the following notations

$$R_{s}; (i!_{n}) = \frac{@W_{s}}{@Z_{(i!_{n})}} s;$$

$$S_{s}(i!_{n}) = \frac{@(i!_{n})}{@W_{s}} s;$$

and $_{n}(q) = G^{-1}(i!_{n}) + G(i!_{n})_{0}^{-1}(q;i!_{n})$. In Eqs. (23)-(24) the spin indices of the G reen function and the self energy are on itted since they are in the paramagnetic phase. The derivatives in Eqs. (23)-(24) can be calculated explicitly. Straightforward calculations give

$$\frac{(\underline{0} (\underline{i!}_{n}))}{(\underline{0}W_{s})} = \frac{1}{(Z (\underline{i!}_{n}) + sJ_{H} U)A (\underline{i!}_{n})};$$
(25)

$$\frac{(i!_n)}{(G(i!_n))} = \frac{A_G(i!_n)}{A(i!_n)};$$
(26)

$$\frac{@W_{s}}{@Z_{(i!_{n})}} = \frac{W_{s}}{Z_{(i!_{n})} + sJ_{H}} \quad W_{s}G(i!_{n});$$
(27)

where

$$A_{G}(i!_{n}) = \frac{X_{S}}{(Z_{G}(i!_{n}) + SJ_{H} - U_{S})^{2}};$$

$$A_{G}(i!_{n}) = \frac{X_{S}}{(Z_{G}(i!_{n}) + SJ_{H} - U_{S})^{2}} [Z_{G}(i!_{n}) + SJ_{H} - U_{S} - G_{H} - U_{S}];$$

In such the way, Eqs. (19)-(24) fully determ ine the susceptibilities, once the self-consistent equations of the DM FT are solved. The charge or spin correlation function diverges whenever b (q) diverges, which happens when the determ inant

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of \oint (q) vanishes. The divergence indicates the instability of the disordered param agnetic state. The q dependence of the susceptibilities comes entirely from _n (q), and hence from the bare susceptibility _0(q;i!_n). W ithin the DMFT^{16,22} in the in nite dimension limit all of the q dependence of the bare susceptibility can be summarized in a single parameter X = $\int_{a=1}^{d} \cos q = d$. One can show that^{16,22}

$${}_{0}(q;i!_{n}) = {}_{0}(X;i!_{n}) = \frac{1}{1 X^{2}} \int_{1}^{Z_{+1}} d \frac{()}{i!_{n} + (i!_{n})} F_{1} \frac{i!_{n} + (i!_{n}) X}{1 X^{2}};$$

where $F_1(z) = \begin{bmatrix} R \\ d \end{bmatrix}$ ()=(z) is used to denote the Hilbert transform. Now the instability of the disordered param agnetic phase happens whenever the determ inant of $\oint (X)$ vanishes at a certain value X. In particular, X = 1 corresponds to the checkerboard zone-boundary point q = (;;:::;) and the corresponding instability leads either to the charge checkerboard phase or to the antiferrom agnetic phase at low tem perature. X = 1 corresponds to the uniform zone center point q = 0 and the corresponding instability leads to a charge segregation phase or FM phase at low tem perature.

IV . NUMERICAL RESULTS

First, we consider the magnetic instability. In this case we calculate the spin correlation function as a function of X and temperature T. A divergence of the spin correlation function indicates a magnetic instability. For most values of $J_{\rm H}$, U and $n_{\rm e}$ the spin correlation function diverges only at X = 1. In Fig. 1 we plot the typical behavior of the spin correlation function. The divergence of the spin correlation function at X = 1 indicates the FM stability. This means the FM state is established at low tem perature. How ever for sm all values of $J_{\rm H}$ and $n_{\rm e}$ closed to 1, the spin correlation function also diverges at Х = 1.^{30,31} This divergence indicates the stability of the antiferrom agnetic phase at low tem perature. In this paperwe only consider the FM phase induced by the DE mechanism and its coexistence with CO phases. Thus in the rest of paper we consider the FM stability only. In Fig. 2 we present the FM transition tem perature $T_{\rm F}\,$ as a function of U and $n_{\rm e}$ for various values of $J_{\rm H}$. $T_{\rm F}$ is determined from the vanishing condition of the determ inant of $\oint (X)$ at X = 1. Fig. 2 (a) show s that the critical

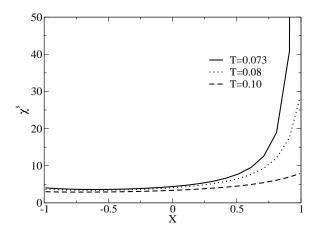


FIG.1: The spin correlation function as a function of X at di erent tem peratures ($n_e = 0.5$, $J_H = 2$, U = 0.5).

tem perature T_F decreases as increasing U and increases as increasing J_H . One expects in the limit J_H ! 1 the FM transition temperature reaches its maximum value for xed U. For xed J_H the FM transition temperature is maximum if there is no JT distortion (i.e. U = 0). The JT distortion splits the energy level of M n ions, and

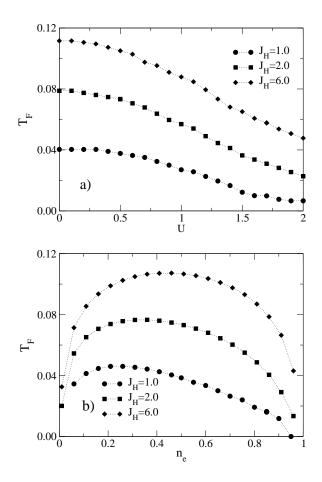


FIG. 2: The FM transition temperature $T_{\rm F}$ as a function of U [(a)n_e = 0.5] and as a function of n_e [(b)U = 0.5] for various values of $J_{\rm H}$.

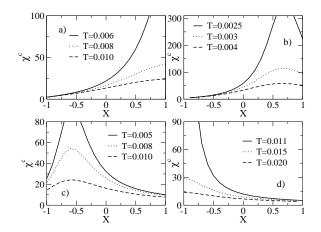


FIG.3: The charge correlation function as a function of X at di erent temperatures. (a) $J_H = 0.1$, (b) $J_H = 0.2$, (c) $J_H = 0.4$, (d) $J_H = 0.5$. In all gures U = 1.0, $n_e = 0.6$.

this leads to suppress the FM transition temperature. This reduction of the FM transition temperature due to distortion is gradually signi cant already at intermediate values of U. In Figure 2 (b) we also present the FM transition temperature as a function of doping n_e . In the lim it $J_{\rm H}$! 1, the FM transition temperature is maximum at half doping n_e = 0.5 21 H owever, for nite $J_{\rm H}$ its maximum shifts away from the half doping, to lower doping region.

Next, we consider the charge ordering instability. In this case, we study the divergence of the charge correlation function in the hom ogeneous param agnetic phase. In Fig. 3 we plot the typical behaviors of the charge correlation function. They show that the charge correlation function m ay diverge at X = 1, X = 1 or at an intermediate value 1 < X < 1. The divergence at X = 1 indicates the checkerboard charge ordered state established at low tem perature, while the divergence at X = 1indicates the segregated state established at low tem perature. The divergence at an interm ediate value of X indicates the charge ordered phase being incom m ensurate at low tem perature. The charge ordering critical tem perature $T_{\rm c}$ is determined from the vanishing condition of the determ inant of Φ (X). However, one notices that for xed values of $J_{
m H}$, U and ${
m n_e}$ the determ inant of Φ (X) m ay vanish at di erent X and tem perature T. Hence, we obtain the critical temperature $T_c(X)$ as a function of X . However, this does not indicate the stability of many charge ordered phases at low tem perature. For certain values of J_H , U and n_e there is only one charge ordering transition which happens at the maximum temperature T_{c} among T_{c} (X). Below this temperature T_{c} , although the charge correlation function m ay still diverge at other values of X, the divergence does not indicate a charge ordering, because the assumption of disordered phase is not valid anym ore. Therefore the charge ordering critical tem perature is determ ined not only from the vanishing

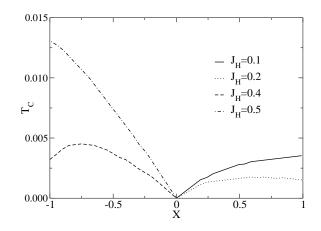


FIG. 4: The dependence of $T_{\rm c}$ on X in case of U = 1:0, $n_{\rm e}$ = 0:6 with various values of $J_{\rm H}$.

condition of the determ inant of $\oint (X$), but also from the maximum condition 16

$$T_c = \max_{fX g} T_c (X)$$

The corresponding value of X at which $T_{\rm c}$ (X) is maximum determ ines the charge arrangement of the low tem – perature phase. In Fig. 4 we plot function $T_{\rm c}$ (X) for dierent values of $J_{\rm H}$. It shows that for xed $J_{\rm H}$, U, $n_{\rm e}$ we always nd a unique maximum $T_{\rm c}$. For small values of $J_{\rm H}$ we obtain the segregated state at low tem perature. For large values of $J_{\rm H}$ the checkerboard ordered phase is observed. In an intermediate regime we also nd an incommensurate charge ordering phase transition. In Fig. 5 we plot the charge ordering critical temperature as a function of U for various values of $J_{\rm H}$. It shows that

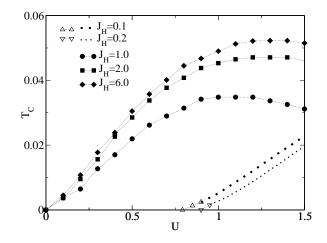


FIG. 5: The critical temperature of charge ordered phase transition as a function of U ($n_e = 0.5$). The lled (opened) sym bols and the dotted lines correspond to the checkerboard (incom m ensurate) charge ordered phase and segregated phase, respectively.

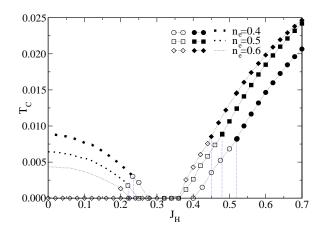


FIG.6: The charge ordering critical tem perature T_c as a function of J_H (U = 1.0). The lled (opened) symbols and the dotted lines correspond to the checkerboard (incommensurate) charge ordered phase and the segregated phase, respectively.

the checkerboard ordered phase is established for large values of $J_{\rm H}$. As increasing U , the critical temperature

rst increases, reaches a maximum value, and then decreases. The behavior of the critical tem perature is sim ilar to the one obtained in the FK model.²⁹ For small values of $J_{\rm H}$ the checkerboard CO phase disappears and the segregated phase or incom m ensurate CO phase m ay be established depending on the value of U , as shown in Fig. 5. Figure. 5 also shows that the segregated phase is established at large values of U, while the incommensurate phase is established at sm aller values of U. One notices that the segregated phase detected from the divergence of the charge correlation function constitutes a continuous phase transition. However, the phase transition is indeed rst order.^{16,32} It can be shown by considering the free energy and using a M axwell construction at low tem perature.^{16,32} U sually, the critical tem perature of the rst order phase transition is higher than the one obtained from the divergence of the charge correlation function.^{16,32}

In Fig. 6 we plot the critical temperature T_c as a function of J_H for various doping n_e . It shows that the checkerboard charge ordered phase is established at large values of J_H and disappears at sm all J_H . Its critical tem perature increases as increasing $J_{\rm H}$. In contrast, the segregated phase is established at sm all values of J_{H} and its critical tem perature decreases as increasing J_{H} . For interm ediate values of J_{H} , both the checkerboard CO $% J_{\text{H}}$ and segregated phases disappear, and an incom m ensurate CO phase is established. In Fig. 7 we plot the critical tem perature T_c as a function of doping n_e for various values $of J_{H}$. For large values $of J_{H}$ the checkerboard CO phase is established, and its critical tem perature reaches m aximum at half doping $n_e = 0.5$. For interm ediate values of $J_{\rm H}$, the CO phase is established at large doping $n_{\rm e} > 0.5$, and disappears at sm aller doping. Instead of the checker-

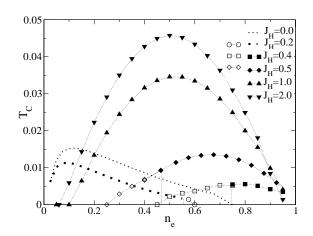


FIG.7: The charge ordering critical tem perature T_c as a function of n_e (U = 1:0). The led (opened) symbols and the dotted lines correspond to the checkerboard (incommensurate) charge ordered phase and the segregated phase, respectively.

board CO phase, an incom m ensurate phase appears. For sm all values of $J_{\rm H}\,$ only the segregated phase appears at sm all doping. At large doping the segregated phase also disappears.

W e sum m arize the above results with the phase diagram in Fig. 8 which plots the regions of stability for di erent charge ordered phases. The stability is determined by the symmetry label X of the initial ordered phase as the tem perature is low ered to the rst instability at T_c . Furtherm ore, we assume that the symmetry labelX of the ordered phase does not change as the tem perature lowered from T_c to zero. Actually, the phase diagram is an approximation of the zero temperature phase diagram .¹⁶ The phase boundaries may change as one reduces the tem perature from T_c to zero since the behaviors of incom m ensurate phases at low tem perature are not able to be studied within the present approach. M oreover, the phase boundaries m ay also change if there are rst-order phase transitions which may happen with the segregation phases. The phase diagram shows that the incommensurate phases is stabilized in bu er zones between the disordered and checkerboard CO phase or between the disordered and segregated phase. The segregated phase exists only for sm all values of $J_{\rm H}$. For large values of J_H the checkerboard CO phase is stabilized. So far, we have obtained di erent charge ordered phases depending on the value of J_H , U and doping n_e . On the other hand, the system always exhibits the FM stability. Although the FM transition m ay happen rst, in the FM phase the charge density still rem ains hom ogeneous and the charge correlation function is still norm al as in the hom ogeneous param agnetic phase. Hence one can use the charge instability signal in the high tem perature hom ogeneous phase as the signal of charge ordering even if the system is already in the FM phase. Indeed, the charge ordering critical tem perature detected from the charge order parameter in the CO-FM state coincides with the

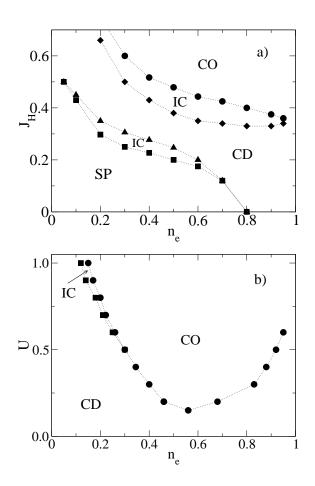


FIG. 8: Charge ordering phase diagram s: (a) U = 1; (b) $J_{\rm H} = 1$. The shorthand CO denotes the checkerboard charge ordered phase; IC, the incom mensurate phase; SP, the segregated phase, and CD, the charge disordered phase.

one calculated from the instability of the charge correlation function in the hom ogeneous param agnetic phase.²¹ In such the way, the FM state coexists with di erent charge ordered phases for appropriate doping and distortion. One notices that in the previous studies 31,33,34,35 a rich phase diagram which includes spin, charge and orbital ordered phases was also obtained. There is also a coexistence of the FM phase with checkerboard CO phase due to the Jahn-Teller phonons.^{31,33,34,35} In particular, the ferrom agnetic CO phase is stabilized for large Jahn-Teller coupling and in nite Hund coupling. The conditions are in an agreement with the phase diagram in Fig. 8. However, in the previous studies 31,33,34,35 only a phase separation between di erent magnetic phases was considered. A separation of charge ordered phases has not been addressed. In the present paper, a charge segregated phase coexisting with the FM phase is obtained theoretically. The phase is a phase separated mixture of two types of M n sites with di erent local geom etric structures. The regime of the phase separation is particularly interesting, and possible consequences of its existence m ay be relevant to the experimental observations.⁸ However, the segregated phase appears only for weak Hund coupling and strong distortion. There is also a possible coexistence of the two segregated phases, one of which is between the magnetic phases, and the other is between the charge ordered phases. However, we leave the problem for further study.

V. CONCLUSION

In the present paper we have considered the doping and distortion e ect on the double-exchange ferrom agnetism . By employing the DMFT we have exactly calculated the charge and spin correlation function. A long range order is determ ined from the divergence signal of the correlation functions. The obtained results show that the system exhibits various phases which include the FM, checkerboard CO, incommensurate CO and segregated phases. In particular, the FM phase can coexist with the checkerboard CO phase for large values of $J_{\rm H}\,$ and with the segregated phase for small values of $J_{\rm H}$. The incom m ensurate phases appear in the bu er zones between the regions of the charge ordered phases with di erent sym m etries. It is interesting to note that experim ents have observed both the CO - FM state⁵ and charge segregated phase.⁸ The phase separation between di erent charge ordered phases is a novel regime in manganites. By including the distortion e ect in manganites via the Falicov-K in ball interaction we have simulated the charge segregated phase. The phase diagram swere found to clearly distinguish regions with robust CO-FM correlations and charge phase separation. However, manganites are too complicated of a system to be completely described by this simple model. In particular, experiments have observed inhom ogeneous regions with di erent long-range orders.⁵ The study of the properties is beyond the capacity of the present method.

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